



# PJS6404

## 30V N-Channel Enhancement Mode MOSFET

**Voltage**

**30 V**

**Current**

**6.8A**

### Features

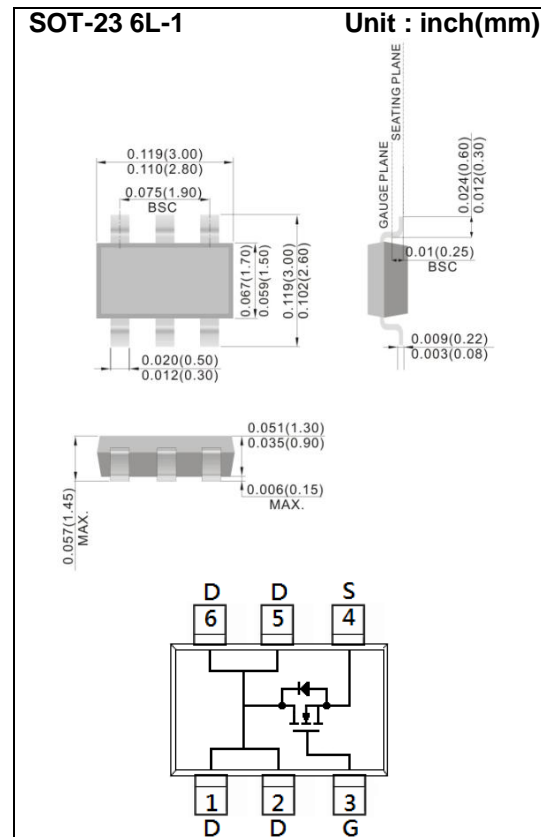
- RDS(ON) , VGS@10V, ID@6.8A<32mΩ
- RDS(ON) , VGS@4.5V, ID@4.3A<47mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc..
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-23 6L-1 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S04

SOT-23 6L-1

Unit : inch(mm)



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER  | SYMBOL                            | LIMIT                | UNITS |
|--|-----------------------------------|----------------------|-------|
| Drain-Source Voltage                             | V <sub>DS</sub>                   | 30                   | V     |
| Gate-Source Voltage                              | V <sub>GS</sub>                   | ±20                  | V     |
| Continuous Drain Current                         | I <sub>D</sub>                    | 6.8                  | A     |
| Pulsed Drain Current                             | I <sub>DM</sub>                   | 27.2                 | A     |
| Power Dissipation                                | P <sub>D</sub>                    | T <sub>a</sub> =25°C | 2     |
|  |                                   | Derate above 25°C    | 16    |
| Operating Junction and Storage Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -55~150              | °C    |
| Typical Thermal resistance                       | R <sub>θJA</sub>                  | 62.5                 | °C/W  |
| - Junction to Ambient (Note 3)                   |                                   |                      |       |



# PJS6404

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION   | MIN. | TYP.     | MAX.      | UNITS      |
|---|--------------|--|------|----------|-----------|------------|
| <b>Static</b>   |              |  |      |          |           |            |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$  | 30   | -        | -         | V          |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$  | 1.0  | 1.4      | 2.1       | V          |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=10V, I_D=6.8A$   | -    | 26       | 32        | m $\Omega$ |
|   |              | $V_{GS}=4.5V, I_D=4.3A$  | -    | 38       | 47        |            |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=30V, V_{GS}=0V$  | -    | 0.01     | 1         | $\mu A$    |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$  | -    | $\pm 10$ | $\pm 100$ | nA         |
| <b>Dynamic</b>  |              |  |      |          |           |            |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=15V, I_D=6.8A,$<br>$V_{GS}=10V$ (Note 1,2)                   | -    | 7.8      | -         | nC         |
| Gate-Source Charge                                    | $Q_{gs}$     |  | -    | 1.2      | -         |            |
| Gate-Drain Charge                                     | $Q_{gd}$     |  | -    | 1.5      | -         |            |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=15V, V_{GS}=0V,$<br>$f=1.0\text{MHz}$                        | -    | 343      | -         | pF         |
| Output Capacitance                                    | $C_{oss}$    |  | -    | 48       | -         |            |
| Reverse Transfer Capacitance                          | $C_{rss}$    |  | -    | 34       | -         |            |
| <b>Switching</b>                                      |              |  |      |          |           |            |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=15V, I_D=6.8A,$<br>$V_{GS}=10V,$<br>$R_G=6\Omega$ (Note 1,2) | -    | 3.1      | -         | ns         |
| Turn-On Rise Time                                     | $t_r$        |  | -    | 40       | -         |            |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |  | -    | 38       | -         |            |
| Turn-Off Fall Time                                    | $t_f$        |  | -    | 39       | -         |            |
| <b>Drain-Source Diode</b>                             |              |  |      |          |           |            |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---  | -    | -        | 2.0       | A          |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=1.0A, V_{GS}=0V$  | -    | 0.75     | 1.2       | V          |

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

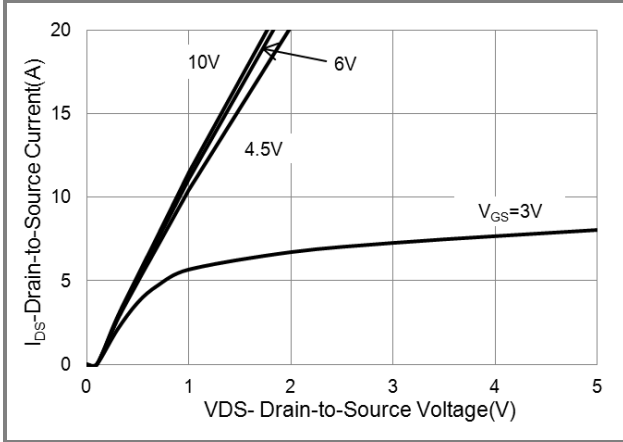


Fig.1 On-Region Characteristics

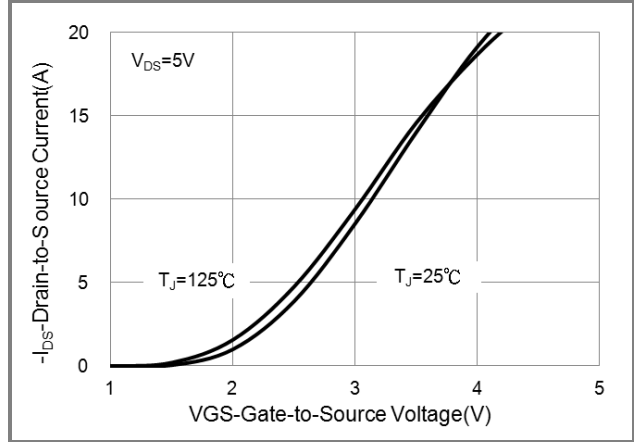


Fig.2 Transfer Characteristics

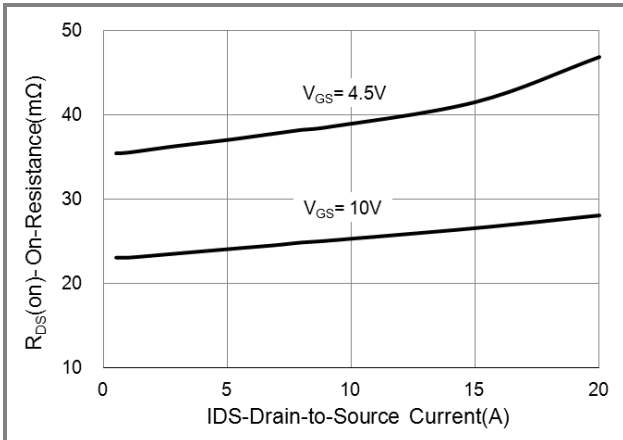


Fig.3 On-Resistance vs. Drain Current

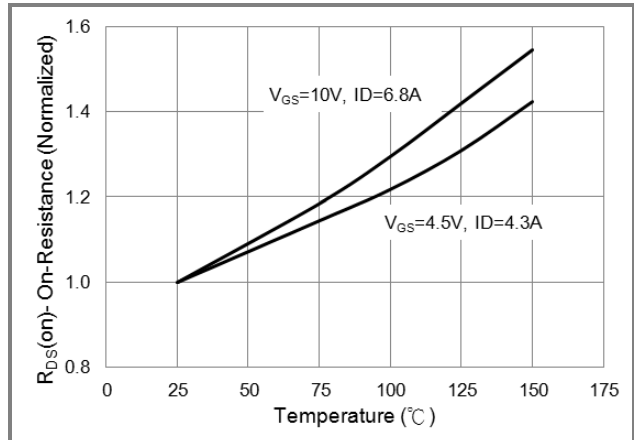


Fig.4 On-Resistance vs. Junction temperature

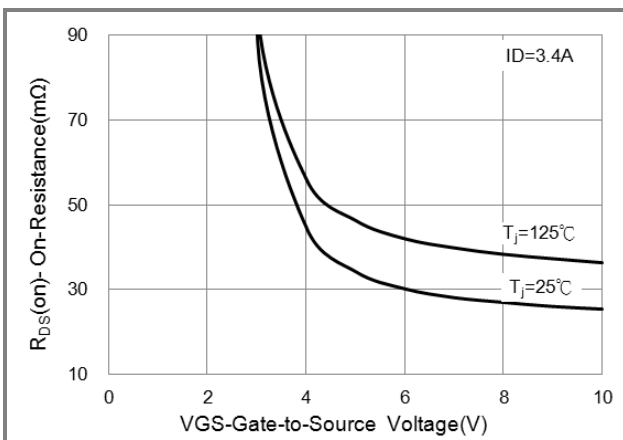


Fig.5 On-Resistance Variation with VGS.

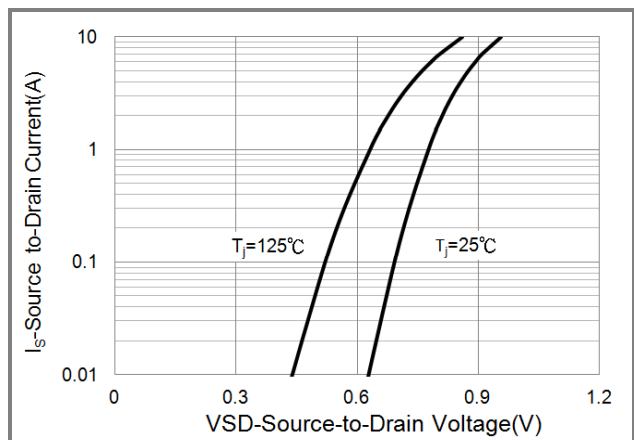


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

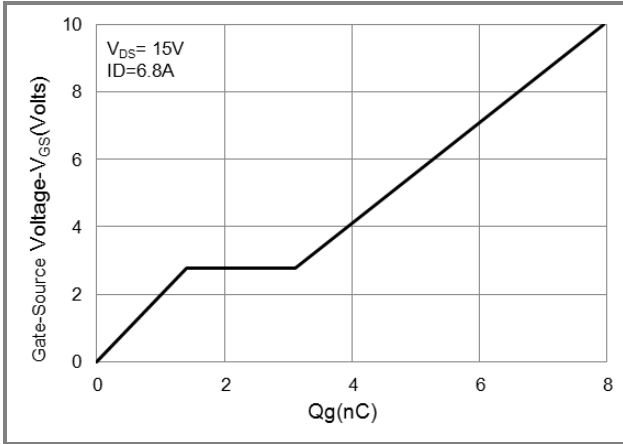


Fig.7 Gate-Charge Characteristics

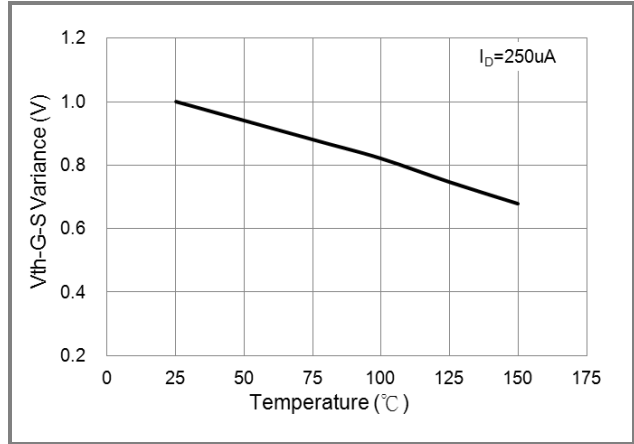


Fig.8 Threshold Voltage Variation with Temperature.

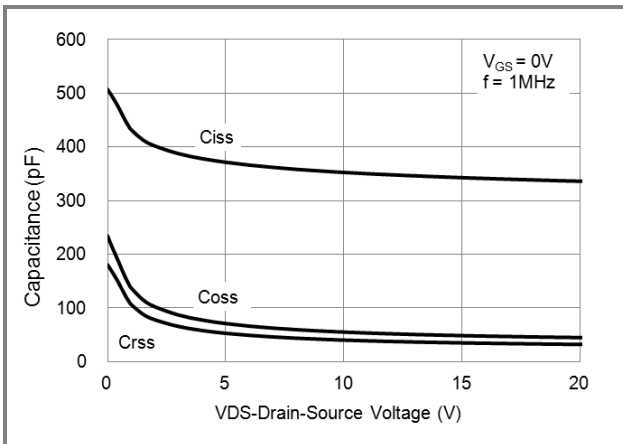


Fig.9 Capacitance vs. Drain-Source Voltage.

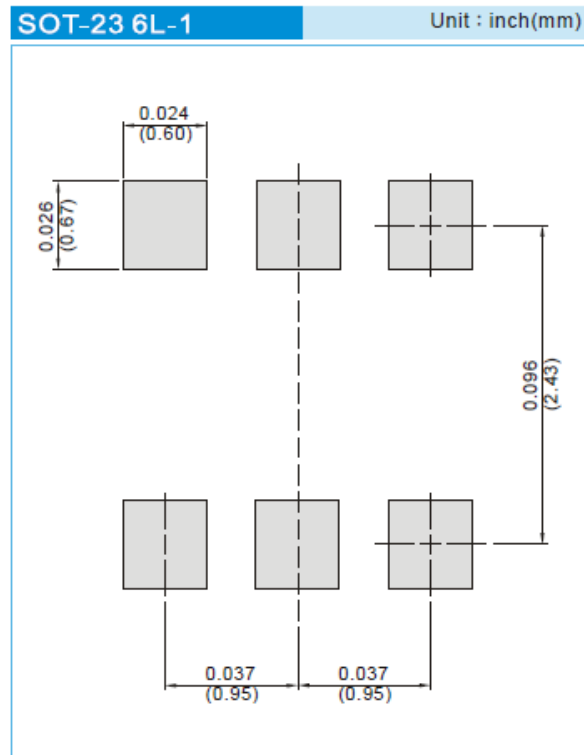


# PJS6404

## PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type     | Marking | Version      |
|----------------------|--------------|------------------|---------|--------------|
| PJS6404_S1_00001     | SOT-23 6L-1  | 3K pcs / 7" reel | S04     | Halogen free |

## MOUNTING PAD LAYOUT





## **PJS6404**

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